Features

- Ultra small package: 1.0x0.6x0.5mm
- Low capacitance: 4pF typical
- Ultra low leakage: nA level
- Low operating voltage: 5V
- Low clamping voltage
- 3-pin leadless package
- Up to 2-line protects
- Complies with following standards:
  - – IEC 61000-4-2 (ESD) immunity test
    - Air discharge: ±15kV
    - Contact discharge: ±12kV
  - – IEC61000-4-4 (EFT) 40A (5/50ns)
- RoHS Compliant

Applications

- Cellular Handsets and Accessories
- Notebooks and Handhelds
- Personal Digital Assistants
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players, Keypads, Side Keys, LCD

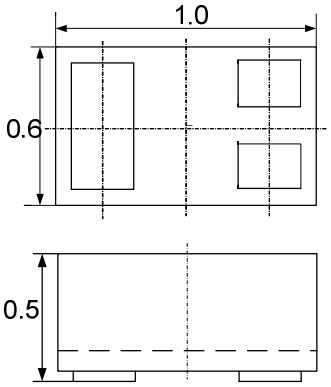
Mechanical Characteristics

- Package: DFN1006-3 (1.0×0.6×0.5mm)
- Lead Finish: NiPdAu
- Case Material: “Green” Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram

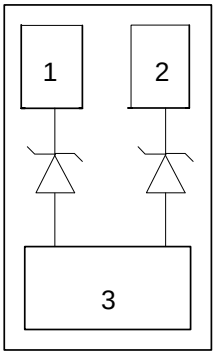
Description

The ESD0521X4 is a 2-line uni-directional TVS diode,utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines.The ESD0521X4 has a low capacitance with a typical value at 4pF, and complies with the IEC 61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size, ultra-low capacitance and high ESD surge protection make ESD0521X4 an ideal choice to protect cell phone, digital video interfaces and many other portable applications.

Dimensions and Pin Configuration



Package Dimensions



Circuit and Pin Schematic

Part Number Code

E	S	D	0	5	1	1	L	1
1	2	3	4	5	6	7	8	9

Product Type	
ESD	TSK Electrostatic suppressor ESD Type

Reverse Working Voltage（V）	
3V3	3.3V
05	5V
16	16V

Line	
1	1-Line
2	2-Line
3	3-Line

directional	
0	Bi
1	Uni

Capacitance Type	
L	Low
X	Normal

Size	
1	0201
2	0402
3	DFN0603
4	DFN1006

★ Code 4 to 9 is optional

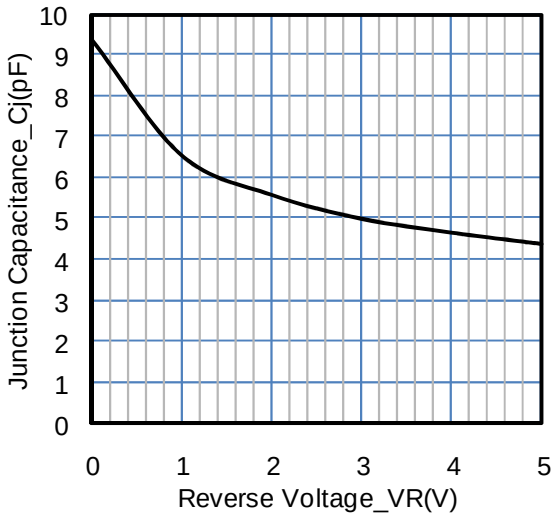
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
ESD per IEC 61000−4−2 (Air) ESD per IEC 61000−4−2 (Contact)	V_{ESD}	±15 ±12	kV
Operating Temperature Range	T_J	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

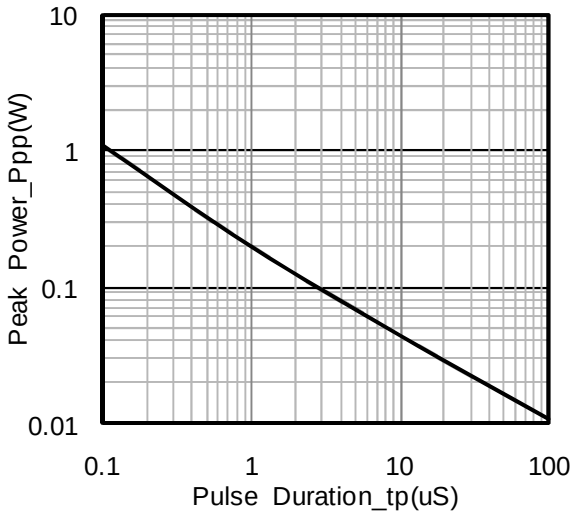
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			5	V	Pin 1 or pin 2 to pin 3 and between pin 1 and pin 2
Breakdown Voltage	V_{BR}	6			V	I_T = 1mA, pin 1 or pin 2 to pin 3 and between pin 1 and pin 2
Reverse Leakage Current	I_R			0.5	uA	V_{RWM} = 5V, Pin 1 or pin 2 to pin 3 and between pin 1 and pin 2
Clamping Voltage	V_C			10	V	I_{PP} = 1A (8 x 20µs pulse), pin 1 or pin 2 to pin 3
Junction Capacitance	C_J			5	pF	VR = 0V, f = 1MHz, between pin 1 and pin 2
Junction Capacitance	C_J			10	pF	VR = 0V, f = 1MHz, pin 1 or pin 2 to pin 3

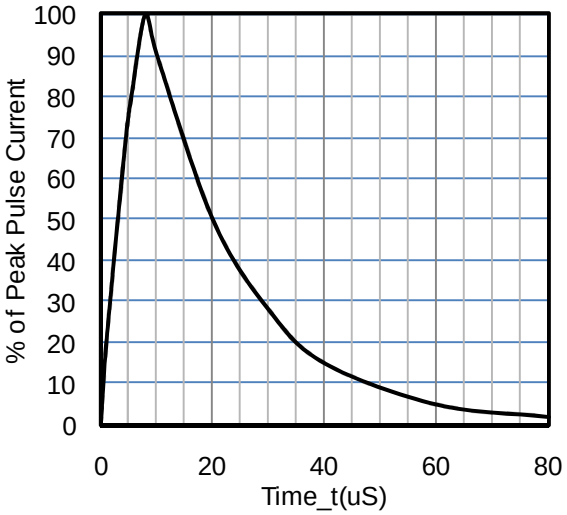
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



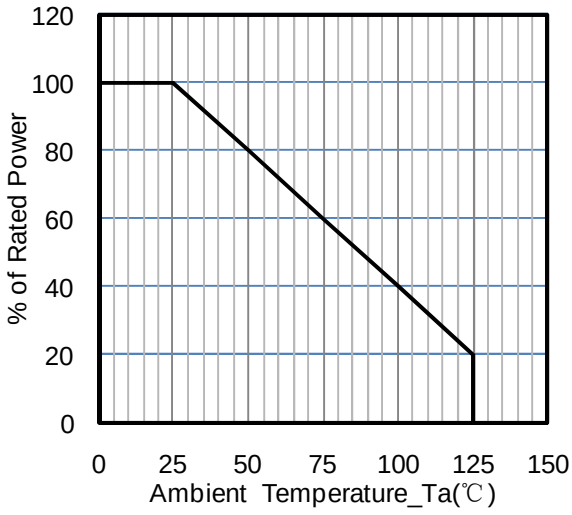
Junction Capacitance vs. Reverse Voltage



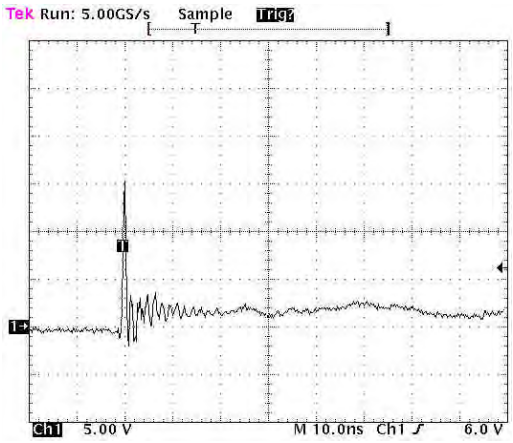
Peak Pulse Power vs. Pulse Time



8 X 20uS Pulse Waveform



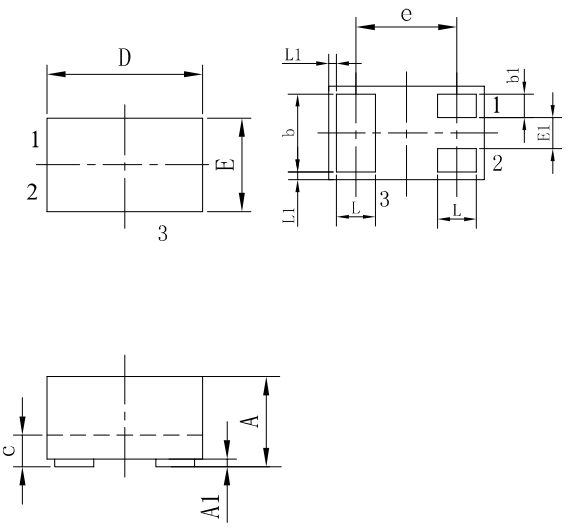
Power Derating Curve



ESD Clamping Voltage

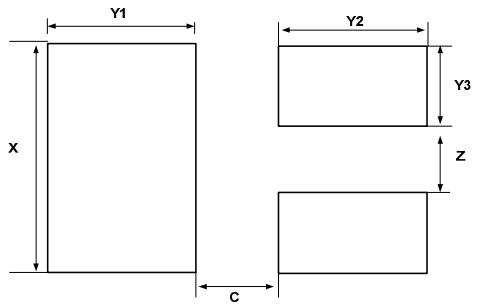
8 kV Contact per IEC61000−4−2

DFN1006-3 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
b1	0.10	0.15	0.20	0.004	0.006	0.008
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
E1	0.15	0.20	0.25	0.006	0.008	0.010
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05 REF			0.0002 REF		

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	0.25	0.010
X	0.65	0.024
Y1	0.50	0.020
Y2	0.50	0.020
Y3	0.25	0.010
Z	0.20	0.008

Ordering Information

Part Number	Packaging	Reel Size
ESD0521X4	5000/Tape & Reel	7 inch